

SYNTHESIS OF THE CuInSe₂ THIN FILMS FOR SOLAR CELLS USING SHS TCHNIQUE AND THERMAL EVAPORATION

L. Saad Hamideche ^{a,*}, A. Amara ^a, F; Boutarfa ^b, A.Boussoukssou ^c, A. Benaldjia ^a, A. Drici ^a, N. Benslim^d.

^a Laboratoire d'Etude et de Recherche des Etats Condensés (LEREC), Département de Physique, Faculté des Sciences, Université Badji Mokhtar , Annaba, Algérie

^bComplex of Arcielor Metal of Elhadjar, Annaba , Algeria.

^c LAMP, Université de Nantes, 2 Rue de Hossinière, BP 92208. Nantes CEDEX 3, 44322, FRANCE.

^d Laboratoire d'Etude de Surfaces et Interfaces de la Matière Solide (LESIMS), Département de Physique, Faculté des Sciences, Université Badji Mokhtar, Annaba, Algérie.

* Département de Physique, Faculté des Sciences, Université Mentouri, Constantine, Algérie.

Abstract: The samples of semi conductors of CuInSe₂ were prepared by self propagating high temperature synthesis (SHS) and direct thermal evaporation onto pr-cleaned glass substrates, using a BALZERS coating unit. The as deposited films were annealed in a vacuum at different temperatures. The structural characterization of the as-deposited CuInSe₂ films of various thicknesses has been carried out by X-ray diffraction method. The diffractogram revealed that the CuInSe₂ films are polycrystalline in nature with chalcopyrite structure. The surface morphology of the as-deposited CuInSe₂ thin films has been studied using scanning electron microscope. The transmittance characteristics of the CuInSe₂ films have been studied using double beam spectrophotometer in the wavelength range 4000–15000A°. The absorption coefficient has been found to be very high and is of the order of 10⁵–10⁶ m⁻¹. CuInSe₂ films are found to have a direct allowed transition and the optical band gap is found to be in the range 0.85–1.05 eV.

Key words: Conversion photovoltaic, CuInSe₂, optical properties, Absorption coefficient.

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